

SEMICONDUCTOR TECHNICAL DATA

SMBB26

SCHOTTKY BARRIER TYPE DIODE

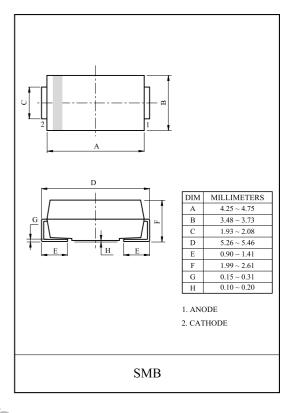
SWITCHING TYPE POWER SUPPLY APPLICATIONS.

FEATURES

- · Low Profile Surface Mount Package.
- · Low Power Loss, High Efficiency.
- For Use in Low Voltage, High Frequency inverters, Free Wheeling, and Polarity Protection Applications.

APPLICATION

- · Switching Power Supply.
- · DC/DC Converter.
- · Home Appliances, Office Equipment.
- · Telecommunication.



MAXIMUM RATING (Ta=25

CHARACTERISTIC	SYMBOL	A ^r ^r	UNIT
Maximum Repetitive Peak Reverse V .ar	PRM	6u	Y
Average Output Rectitifed Current	I_0	2	
Peak One Cycle Surge Forward Current	I _{FSM}	3	A
(Non-Repetitive 60Hz)	15141		
Junction Temperature	T _j	-40	
Storage Temperature Range	T_{stg}	-40 150	

B26

Lot No.

ELECTRICAL CHARACTERISTICS (Ta=25)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Peak Forward Voltage	V_{FM}	I _{FM} =2.0A	-	-	0.65	V
Repetitive Peak Reverse Current I _{RRN}	I	V _{RRM} =Rated, Tj=25	-	-	0.1	mA
	1RRM	V _{RRM} =Rated, Tj=100	-	-	10	mA
Total Capacitance	C_{T}	V _R =4V, f=1MHz	-	-	200	pF
Thermal Resistance	R _{th(j-1)}	Junction to lead	-	-	15	/W

